# NSN 5961-01-564-9795

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Inclosure Material:

Metal

**Overall Length:** 

19.6 millimeters

# Terminal Length:

13.2 millimeters

## **Overall Diameter:**

4.7 millimeters

#### **Function For Which Designed:**

Phototransistor

#### **Mounting Method:**

Terminal

#### Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

70.0 breakdown voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

100.00 nanoamperes zero-gate-voltage source current absolute

# Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector preset

#### **Special Features:**

Lens window; high photo sensitivity; lead (pb)-free component

#### **Terminal Type And Quantity:**

3 pin

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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